Ordering number : ENA0274



## SANYO Semiconductors DATA SHEET

### 2SC6093LS

NPN Triple Diffused Planar Silicon Transistor

# Color TV Horizontal Deflection Output Applications

#### **Features**

- · High speed.
- High breakdown voltage (VCBO=1500V).
- · High reliability (Adoption of HVP process).
- Adoption of MBIT process.
- · On-chip damper diode.

#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO	COM	1500	V
Collector-to-Emitter Voltage	VCEO	.0.0	800	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		5	Α
Collector Current (Pulse)	ICP		12	Α
Collector Dissipation	PC		2.0	W
		Tc=25°C	25	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg	Be (	-55 to +150	°C

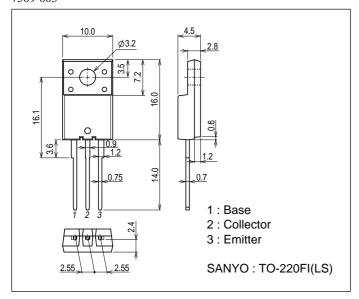
#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Collector Cutoff Current	ІСВО	V <sub>CB</sub> =800V, I <sub>E</sub> =0A			10	μΑ
Collector Cutoff Current	ICES	VCE=1500V, RBE=0Ω			1.0	mA
Collector Sustain Voltage	VCEO(sus)	I <sub>C</sub> =100mA, I <sub>B</sub> =0A	800			V
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0A	40		130	mA
Collector-to-Emitter Saturation Voltage	VCE(sat)1	I <sub>C</sub> =1.35A, I <sub>B</sub> =0.27A	0.1		0.3	V
	V <sub>CE</sub> (sat)2	I <sub>C</sub> =2.7A, I <sub>B</sub> =0.54A	-		2	V
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=2.7A, IB=0.54A			1.5	V
DC Comment Coding	hFE1	VCE=5V, IC=0.5A	10	Tar W	Drain	7 47 9
DC Current Gain	hFE2	V <sub>CE</sub> =5V, I <sub>C</sub> =3A	5.3		7.5	
Diode Forward Voltage	VF	IEC=4A			2	V
Fall Time	tf	IC=1.8A, IB1=0.36A, IB2=-0.72A			0.2	μS

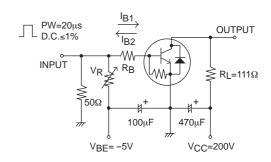
- Any and all SANYO Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO Semiconductor representative nearest you before using any SANYO Semiconductor products described or contained herein in such applications.
- SANYO Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor products described or contained herein.

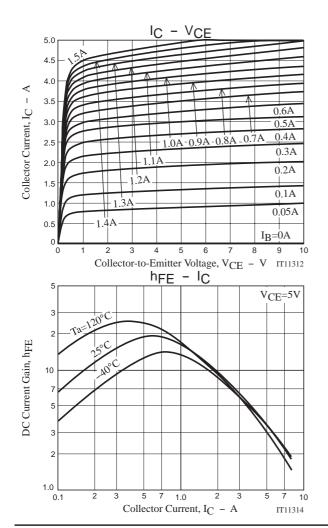
#### **Package Dimensions**

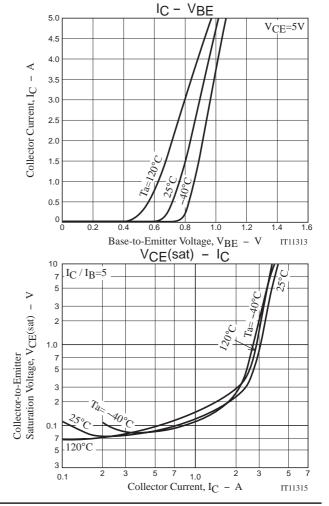
unit : mm (typ) 7509-003



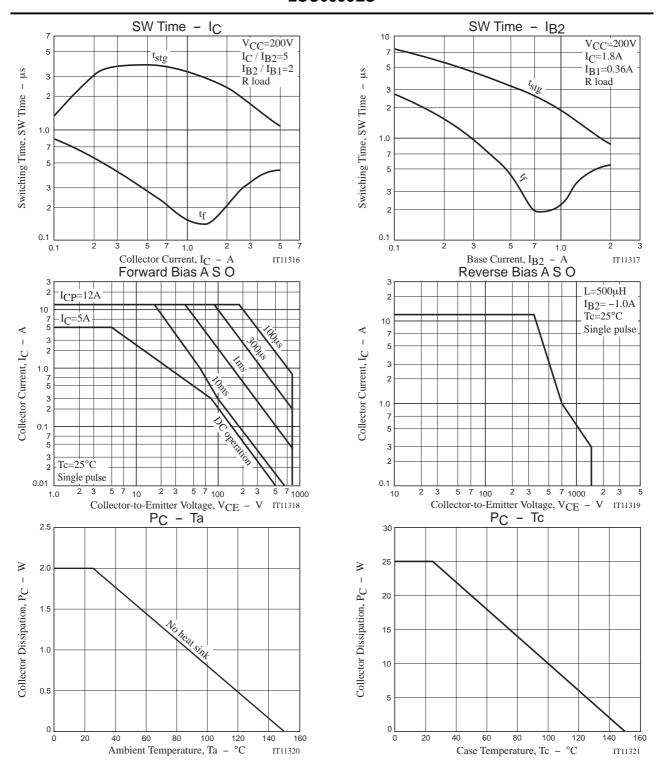
#### **Switching Time Test Circuit**







#### 2SC6093LS



#### 2SC6093LS

- Specifications of any and all SANYO Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor products (including technical data,services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Semiconductor Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of January, 2007. Specifications and information herein are subject to change without notice.